

Guangzhou BDE Technology Inc.
Address: B2-403, Chuangyi Building, 162 Science Avenue, Huangpu District,
Guangzhou 510663, China

Office of Engineering Technology
Federal Communications Commission
7435 Oakland Mills Road
Columbia, MD 21046
USA

Dear Sir/Madam,

We, Guangzhou BDE Technology Inc. Hereby declares the following statement for
PHOENIX TESTLAB TAIWAN LTD.,

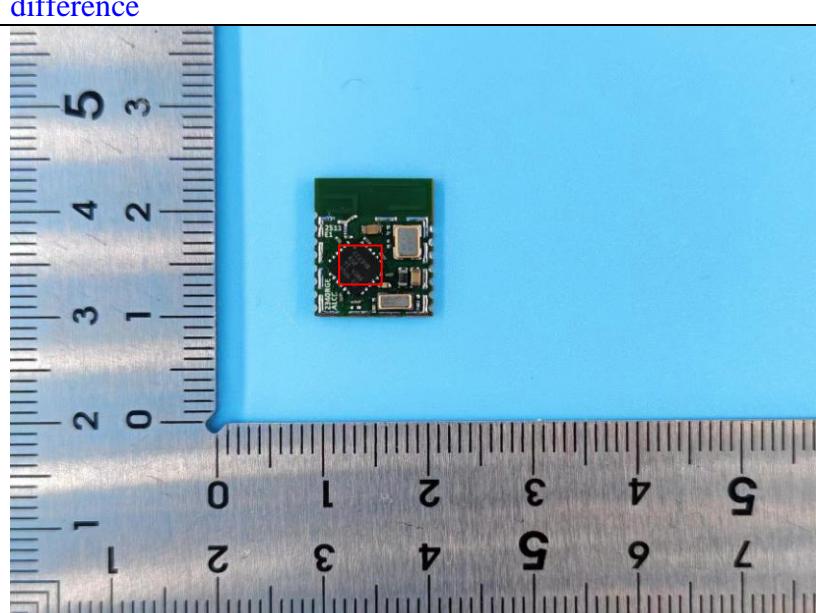
The above models have same PCB board and structure. The difference between the BDE-LE2340R52GEAC and BDE-LE2340R21GEAC models lies in the sizes of their Flash and SRAM of the IC chip. The BDE-LE2340R52GEAC has 512KB of Flash and 36KB of SRAM, while the BDE-LE2340R21GEAC has 256KB of Flash and 28KB of SRAM.

Product Name: BDE BLE Module Based on CC2340R

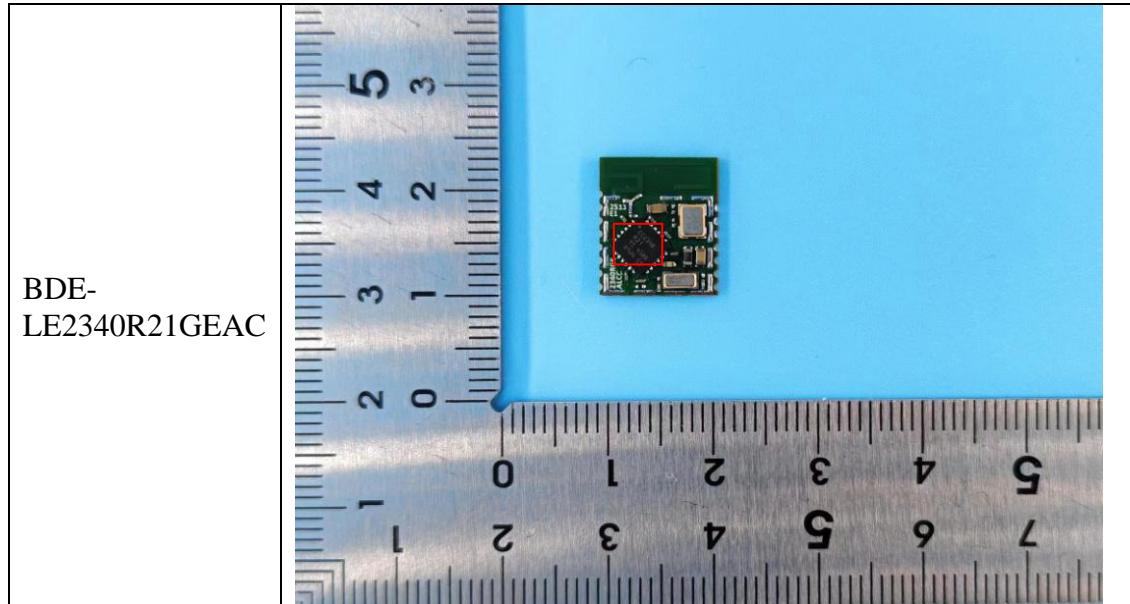
Trade Mark: BDE

Model: BDE-LE2340R52GEAC , BDE-LE2340R21GEAC

1, The difference between the BDE-LE2340R52GEAC and BDE-LE2340R21GEAC models lies in the sizes of their Flash and SRAM of the IC chip as following table

Model	difference
BDE-LE2340R52GEAC	

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Signature: _____ Date: 2025-7-24

Name: Jacky Tian

Title: CEO

Company: Guangzhou BDE Technology Inc.